

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Cheng et al.

Application No. 10/802,186

Confirmation No. 3869

Filed: March 17, 2004

Art Unit: 2811

Title: PROCESS FOR PRODUCING
SEMICONDUCTOR ARTICLE USING
GRADED EPITAXIAL GROWTH

Examiner: Hu, Shouxiang

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Pursuant to 37 CFR 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form, based on Form PTO/SB/08. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

In accordance with 37 CFR 1.98(a)(2)(ii), Applicants have not submitted copies of cited U.S. patents and U.S. patent applications. Applicants submit herewith copies of cited foreign patents and non-patent literature in accordance with 37 CFR 1.98(a)(2).

This Information Disclosure Statement is filed after the mailing date of the first Office Action on the merits, but before the mailing date of a Final Office Action or Notice of Allowance (37 CFR 1.97(c)).

Please charge our Deposit Account No. 07-1700 in the amount of \$180.00 covering the fee set forth in 37 CFR 1.17(p). The Director is hereby authorized to charge any deficiency in the filed fees to our Deposit Account No. 07-1700, under Order No. ASC-025DV2C1.

Date: 8-6-07

Respectfully submitted,

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